### Vishay Semiconductors

### TELUX™

### FEATURES

- High luminous flux
- Supreme heat dissipation: R<sub>thJP</sub> = 90 K/W
- High operating temperature:
  - $T_{amb} = -40 \degree C \text{ to} + 110 \degree C$
- Packed in tubes for automatic insertion
- Luminous flux, forward voltage and color categorized for each tube
- Small mechanical tolerances allow precise usage of external reflectors or light guides
- · Lead (Pb)-free device RoHS-COMPLIANT
- ESD-withstand voltage: up to 1 kV according to JESD22-A114-B
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Compatible with wave solder processes according to CECC 00802 and J-STD-020C
- Automotive qualified

#### PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: TELUX™
- Product series: power
- Angle of half intensity: ± 45°

#### **APPLICATIONS**

- Exterior lighting
- Replacement of small incandescent lamps
- Traffic signals and signs

PARTS TABLE		
PART	COLOR, LUMINOUS FLUX	TECHNOLOGY
VLWTG9900	True green, $\phi_V = 2500 \text{ mIm (typ.)}$	InGaN on SiC

#### DESCRIPTION

The VLWTG9900 is a clear, non diffused LED for applications where high luminous flux is required.

It is designed in an industry standard 7.62 mm square package utilizing highly developed InGaN technology. The supreme heat dissipation of VLWTG9900 allows applications at high ambient temperatures.

All packing units are binned for luminous flux, forward voltage and color to achieve the most homogenous light appearance in application.





### Vishay Semiconductors



ABSOLUTE MAXIMUN	I RATINGS <sup>1)</sup> VLWTG990	00		
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage	I <sub>R</sub> = 10 μA	V <sub>R</sub>	5	V
DC Forward current	$T_{amb} \le 50 \ ^{\circ}C$	١ <sub>F</sub>	50	mA
Surge forward current	$t_p \le 10 \ \mu s$	I <sub>FSM</sub>	0.1	A
Power dissipation		P <sub>V</sub>	230	mW
Junction temperature		Тj	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C
Storage temperature range		T <sub>stg</sub>	- 55 to + 100	°C
Soldering temperature	$t \le 5$ s, 1.5 mm from body preheat temperature 100 °C/ 30 s	T <sub>sd</sub>	260	°C
Thermal resistance junction/ ambient	with cathode heatsink of 70 mm <sup>2</sup>	R <sub>thJA</sub>	200	K/W
Thermal resistance junction/pin		R <sub>thJP</sub>	90	K/W

Note:

<sup>1)</sup>  $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

OPTICAL AND ELECT	RICAL CHARACTERIST	ICS <sup>1)</sup> VLW	TG9900,	TRUE GR	EEN	
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Total flux	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	φv	2000	2500		mlm
Luminous intensity/Total flux	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	Ι <sub>V</sub> /φ <sub>V</sub>		0.7		mcd/mlm
Dominant wavelength	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	λ <sub>d</sub>	509	523	535	nm
Peak wavelength	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	λ <sub>p</sub>		518		nm
Angle of half intensity	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	φ		± 45		deg
Total included angle	90 % of Total Flux Captured	φ		100		deg
Forward voltage	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	V <sub>F</sub>		3.9	4.7	V
Reverse voltage	I <sub>R</sub> = 10 μA	V <sub>R</sub>	5	10		V
Junction capacitance	V <sub>R</sub> = 0, f = 1 MHz	Cj		50		pF
Temperature coefficient of $\lambda_{\text{dom}}$	I <sub>F</sub> = 30 mA	TCλ <sub>dom</sub>		0.02		nm/K

Note:

<sup>1)</sup> T<sub>amb</sub> = 25 °C, unless otherwise specified

LUMINOUS P	LUMINOUS FLUX CLASSIFICATION		
	TRUE	GREEN	
GROUP	LUMINOUS FLUX (MLM)		
	MIN.	MAX.	
D	2000	3000	
E	2500	3600	
F	3000	4200	

#### Note:

Luminous flux is tested at a current pulse duration of 25 ms and an accuracy of  $\pm$  11 %.

The above type numbers represent the order grous which include only a few brightness groups. Only one group will be shipped in one tube (there will be no mixing of two groups on each tube).

In order to ensure availability, single brightness groups will not be orderable. In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped in any one tube.

In order to ensure availability, single wavelength groups will not be orderable.

COLOR CLASSIFICATION			
	TRUE GREEN DOM. WAVELENGTH (NM)		
GROUP			
	MIN.	MAX.	
2	509	517	
3	515	523	
4	521	529	
5	527	535	

Note:

Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of  $\pm$  1 nm.



#### **TYPICAL CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

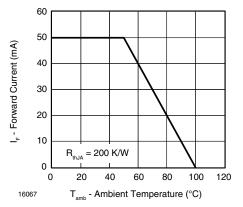


Figure 1. Forward Current vs. Ambient Temperature for InGaN

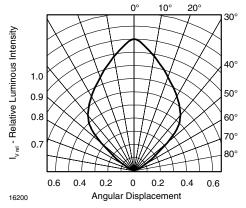


Figure 2. Rel. Luminous Intensity vs. Angular Displacement

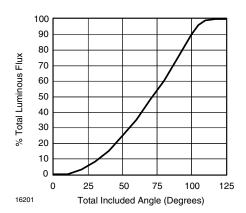


Figure 3. Percentage Total Luminous Flux vs. Total Included Angle for 90 ° emission angle

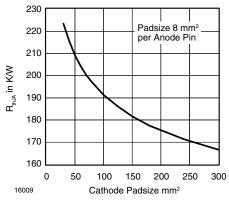


Figure 4. Thermal Resistance Junction Ambient vs. Cathode Padsize

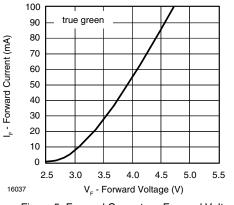


Figure 5. Forward Current vs. Forward Voltage

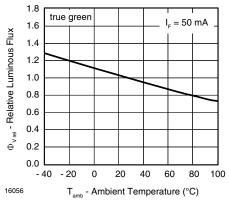


Figure 6. Rel. Luminous Flux vs. Ambient Temperature

# Vishay Semiconductors



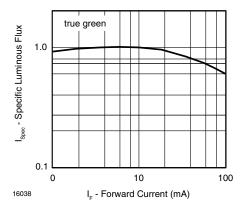


Figure 7. Specific Luminous Flux vs. Forward Current

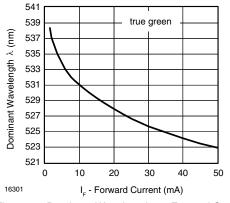


Figure 10. Dominant Wavelength vs. Forward Current

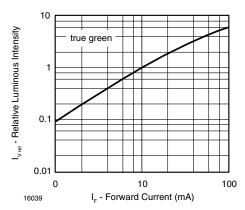
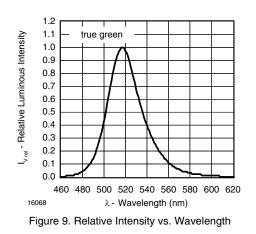


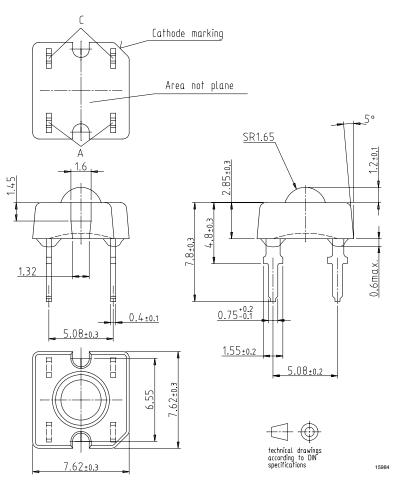
Figure 8. Relative Luminous Intensity vs. Forward Current



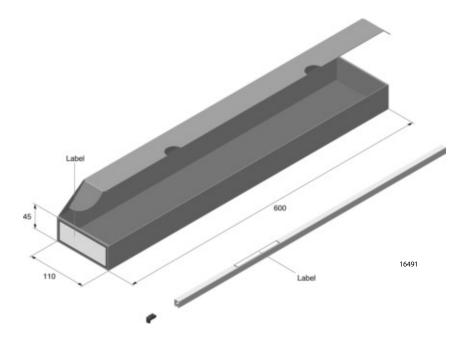


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#### **PACKAGE DIMENSIONS** in millimeters



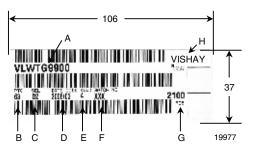
FAN FOLD BOX Dimensions in millimeters





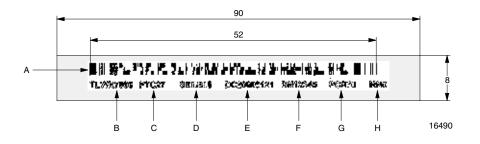
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#### LABEL OF FAN FOLD BOX



- A) Type of component
- B) Manufacturing plant
- C) SEL selection code (bin):
  - e.g.: D = code for luminous intensity group 2 = code for color group
- D) Date code year/week
- E) Day code (e. g. 4: Thursday)
- F) Batch no.
- G) Total quantity
- H) Company code

#### **EXAMPLE FOR TELUX TUBE LABEL** Dimensions in millimeters



- A) Bar code
- B) Type of component
- C) Manufacturing plant
- D) SEL selection code (bin)
  - Digit 1 code for luminous flux group Digit 2 - code for dominant wavelength group Digit 3 - code for forward voltage group
- E) Date code
- F) Batch no.
- G) Total quantity
- H) Company code

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## VLWTG9900 Vishay Semiconductors

#### TUBE WITH BAR CODE LABEL Dimensions in millimeters

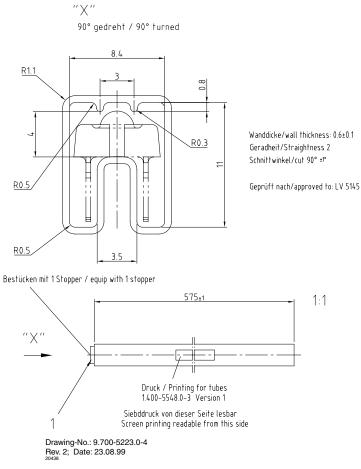


Figure 9. Drawing Proportions not Scaled

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#### **OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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